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## Surface termination passivation of imidazole-based diiodide enabling efficient inverted perovskite solar cells†

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***N*-(3-aminopropyl)-imidazole diiodide (APDI) was introduced on the upper surface of the perovskite for the first time to modulate the terminal groups. The defect traps were suppressed by binding N cations from the APDI with Pb<sup>2+</sup>. Consequently, the optimum APDI-treated device achieved a PCE of 21.41% and exhibited excellent stability.**

Metal-halide perovskite materials are widely employed as photosensitive layers for the study of perovskite solar cells (PSCs) based on exotic semiconductor properties (*e.g.*, tunable bandgap, excellent optical absorption, and high defect tolerance).<sup>1,2</sup> Presently, the power conversion efficiency (PCE) of single-junction PSCs has increased from less than 4% in 2009 to 25.7%.<sup>1–3</sup> Although the PCE of nip-type (regular) PSCs is always higher than that of pin-type (inverted) PSCs during the same period, the inverted PSCs are gradually receiving more attention owing to their lower preparation energy consumption.<sup>3</sup> In addition, MA-free Cs/FA-based perovskite combines excellent stability, which is a desirable material choice for application in PSCs.<sup>4</sup>

The surface of the perovskite film, which is prepared by a solution-based process, suffers from various unavoidable defects (*e.g.*, vacancies, interstitials, anti-site substitutions), resulting from the ionic nature of perovskite materials and the soft crystalline properties.<sup>5</sup> Moreover, the properties of nanoscale-based perovskite films are susceptible to surface effect, making surface modulation engineering an effective means to regulate the chemical environment of the upper surface of perovskite films.<sup>6,7</sup> Consequently, the presence of

the above defects was considered a major factor restricting the further elevation in PSC performance, which not only induced a decrease in PCE by trapping charges to aggravate the nonradiative recombination but also served as the preferential sites for erosion by external factors (*e.g.*, H<sub>2</sub>O, O<sub>2</sub>, and ultraviolet) to accelerate the degradation of perovskite film.<sup>4</sup> To date, studies based on ligand engineering for perovskite surfaces have been broadly reported. For example, Lewis-base molecules with electron-donating groups are frequently employed to reduce uncoordinated Pb<sup>2+</sup> that is considered to be the main source of defects on the perovskite surface due to its lower formation energy.<sup>5,7,8</sup>

Compared to the ligand engineering realized by molecules with electron-donating groups, the ammonium salt-based modification has the advantage of a convenient and efficient process for the passivation step.<sup>9,10</sup> Since the work of interfacial modification by phenethylamine iodide (PEAI) was reported, the investigation of modulating the terminal environment of perovskites by ammonium salts had drawn attention. Amino-corannulene iodides were introduced on the surface of the perovskite by Yang *et al.*, leading to a significant reduction of the Pb<sup>2+</sup> traps owing to the favorable coordination ability between R-NH<sub>3</sub><sup>+</sup> and Pb<sup>2+</sup>.<sup>11</sup> Simultaneously, ammonium diiodide salts, such as ethane-1,2-diamine diiodide, histamine diiodide, have also been adopted as modifiers to mitigate the defect density of perovskite at the top and bottom interface of PSCs.<sup>12,13</sup> However, the above ammonium salts have only one functional group binding to the Pb<sup>2+</sup> traps for passivation. Compared to the wide investigation of passivators with single-acting sites, there are few reports on ammonium salts with dual-functional groups of coordination for the surface modulation of perovskite.

In this study, we introduced the API (*N*-(3-Aminopropyl)-imidazole) diiodide (APDI) on the upper surface of FA<sub>0.83</sub>CS<sub>0.17</sub>Pb(I<sub>0.86</sub>Br<sub>0.14</sub>)<sub>3</sub> film to modulate the terminal chemical environment, and good photovoltaic performance was obtained. Table S1 (ESI†) lists a comparison of the parameters. The bifunctional

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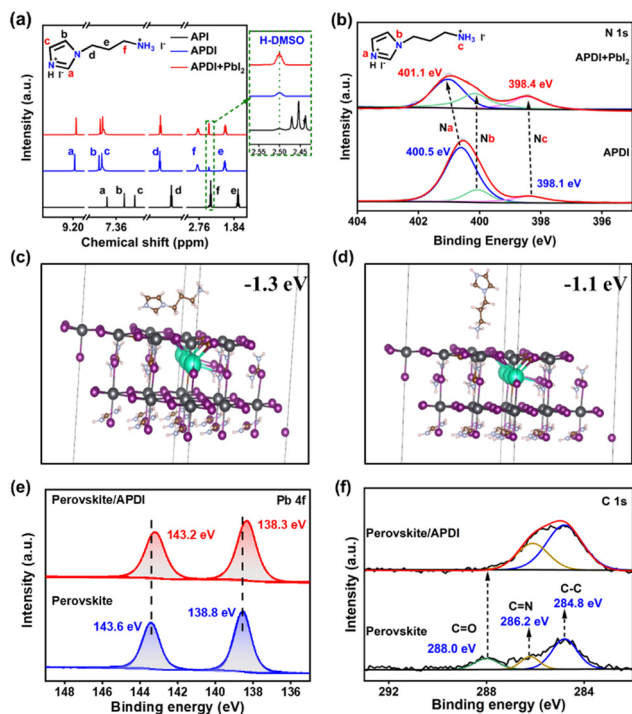
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groups ( $\text{C}=\text{NH}^+$  and  $-\text{NH}_3^{+}$ ) in APDI make it more effective in reducing the  $\text{Pb}^{2+}$  defect on the perovskite surface through bonding to  $\text{Pb}^{2+}$ . Density functional theory (DFT) demonstrated that the N on the imidazole ring in APDI was slightly more inclined to bind to  $\text{Pb}^{2+}$  traps than to N on the branched chain. Moreover, the hydrophobicity of the perovskite films was enhanced by the introduction of APDI with an alkyl chain on the surface. Consequently, the optimum device after APDI modification (target) has an increased PCE, from 20.01% to 21.41%. Additionally, the target devices exhibited excellent stability, maintaining 78% and 90% of the initial PCE after 800 h and 1000 h of aging in air and nitrogen atmospheres, respectively.

A reasonable APDI molecule based on interfacial engineering was designed to achieve synergistic enhancement of PSC performance. Unlike the isopropanol solution of APDI, pure API (which exists as a liquid at room temperature) contacting the perovskite causes rapid decomposition of thin films (Fig. S1a, ESI<sup>†</sup>). The molecular structures of API and APDI are shown in Fig. S1b (ESI<sup>†</sup>), and the details of APDI synthesis are shown in the Experimental Section. The H-NMR results showed that the chemical shifts of H in the iodinated API changed compared to the API. As depicted in Fig. 1a, the differences in chemical shift ( $\Delta\delta_{\text{H}}$ ) between the iodinated API and API at the same position were as follows:  $\Delta\delta_{\text{Ha}} = 1.56$  ppm,  $\Delta\delta_{\text{Hb}} = 0.67$  ppm,  $\Delta\delta_{\text{Hc}} = 0.87$  ppm,  $\Delta\delta_{\text{Hd}} = 0.30$  ppm,  $\Delta\delta_{\text{He}} = 0.35$  ppm, and  $\Delta\delta_{\text{Hf}} = 0.36$  ppm. Among them, the variations in  $\Delta\delta_{\text{Ha}}$ ,  $\Delta\delta_{\text{Hc}}$  and  $\Delta\delta_{\text{Hf}}$  were the most significant, indicating that the N in the

imidazole ring ( $\text{C}=\text{N}$ ) and branched chain ( $-\text{NH}_2$ ) were halogenated. The detailed H-NMR spectra are shown in Fig. S2 (ESI<sup>†</sup>). To further analyze the interaction between APDI and  $\text{PbI}_2$  in the perovskite, X-ray photoelectron spectroscopy (XPS) was performed to obtain the information. As shown in the spectra of N 1s (Fig. 1b), the peaks at 400.5 eV, 400.1 eV, and 398.1 eV can be attributed to Na, Nb, and Nc in the APDI, respectively; however, the signals of Na and Nc were shifted after introducing  $\text{PbI}_2$ , and the Na had a slightly larger offset, which verifies that Na was favored over the Nc to bind to  $\text{Pb}^{2+}$ .<sup>13</sup> By analyzing the H-NMR of APDI and APDI +  $\text{PbI}_2$  (Fig. 1a), the Ha, Hb, and Hc in APDI +  $\text{PbI}_2$  demonstrated chemical shift with  $\Delta\delta_{\text{H}}$  of  $\geq 0.03$  ppm compared to APDI, while the  $\Delta\delta_{\text{H}}$  of Hd, He, Hf is  $\sim 0.02$  ppm, suggesting that there was an interaction between N cations from the imidazole ring and branched chain and  $\text{Pb}^{2+}$ . The former is more prone to bind with  $\text{Pb}^{2+}$ . The density functional theory (DFT) calculations demonstrated that the binding energies of  $-\text{NH}_3^{+}$  and  $\text{C}=\text{NH}^+$  with surface  $\text{Pb}^{2+}$  were  $-1.1$  eV and  $-1.3$  eV, respectively, further confirming the above conclusion (Fig. 1c and d). The Pb 4f spectra from XPS for the perovskite films before and after being treated with APDI are shown in Fig. 1e. The characteristic signals at 138.8 eV and 143.6 eV belonging to  $\text{Pb}^{2+}$  shifted to 138.3 eV and 143.2 eV, respectively, after ADPI treatment, indicating again that APDI can interact with uncoordinated  $\text{Pb}^{2+}$  defect.<sup>4</sup> The XPS spectrum of C1s (Fig. 1f) shows the presence of peaks at 286.2 and 284.8 eV, which can be attributed to the  $\text{C}=\text{N}$  and  $\text{C}-\text{C}$  from the FA<sup>+</sup>. The emerged  $\text{C}=\text{O}$  peak located at 288.0 eV reflects the decomposition of perovskite induced by interaction with air during the process of exposure to ambient conditions. This result implies that the target film may have better resistance to  $\text{H}_2\text{O}$  or  $\text{O}_2$ .<sup>14</sup>

To better capture the performance of the perovskite film without (control) and with (target) APDI treatment, various morphologies and optical characterizations were carried out. Top-view scanning electron microscopy (SEM) showed no particularly significant difference in the grain sizes of the control and target films (Fig. S3, ESI<sup>†</sup>). However, the contact angle of the control film increased from  $57.9^\circ$  to  $76.9^\circ$  after APDI treatment; this may be due to the presence of alkyl chains in APDI, which increased the hydrophobicity of the film surface (Fig. S4a, ESI<sup>†</sup>). The UV-vis absorption spectra demonstrated that the target film had better light absorption, which indicated that the APDI modification contributed to improving the quality of the perovskite film without a change in the band-gap (Fig. S4b–d, ESI<sup>†</sup>). Moreover, the roughness of the perovskite film was reduced from 10.7 nm to 8.19 nm after APDI modification, as observed in the atomic force microscopy (AFM) measurements (Fig. S3c, ESI<sup>†</sup>). The improved surface roughness means that the perovskite/ $\text{C}_{60}$  interface can form better contact, which has the potential to promote efficient charge transport.<sup>14</sup> By steady-state (PL) and time-resolved photoluminescence (TRPL), it could be observed that (Fig. 2a) PL intensity of the target film was significantly enhanced than that of the control film, indicating that the APDI can reduce the nonradiative recombination loss of perovskite by the surface passivation and thus is



**Fig. 1** (a) <sup>1</sup>H-NMR spectra of API, APDI and APDI +  $\text{PbI}_2$ . (b) XPS spectra of N 1s for APDI and APDI +  $\text{PbI}_2$ . (c) and (d) Theoretical models of Cs/FA-based perovskite with molecular surface interaction of  $\text{Pb}^{2+}$  with APDI. XPS spectra of (e) Pb 4f and (f) C 1s for perovskites with and without APDI.

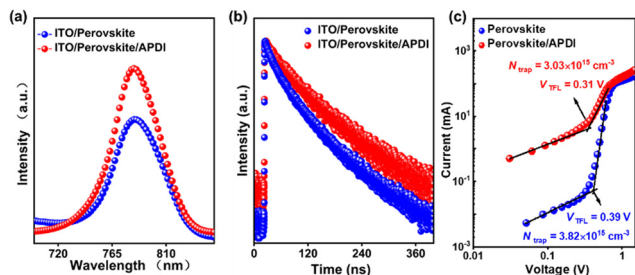


Fig. 2 (a) PL spectra, (b) TRPL and (c) trap density of perovskite without (control) and with (target) APDI.

conductive to improving film quality, which agrees with the results observed from UV-vis. The TRPL spectra were fitted by biexponential function (Fig. 2c and Table S2, details are shown in the Characterization, ESI<sup>†</sup>), and it is found that the average lifetime ( $\tau_{avg}$ ) of the target film was prolonged, further confirming the significant passivation effect of APDI.<sup>6</sup> Moreover, the defect density of perovskite without and with APDI was quantified by applying the space-charge-limited current (SCLC) method.<sup>13</sup> The device structure was ITO/C<sub>60</sub>/perovskite/with or without APDI/C<sub>60</sub>/Au (for more details, see the Characterization in ESI<sup>†</sup>). As shown in Fig. 2c, the calculated  $N_{trap}$  for the control and target devices were  $3.82 \times 10^{15} \text{ cm}^{-3}$  and  $3.03 \times 10^{15} \text{ cm}^{-3}$ , respectively. This proved that APDI could effectively reduce perovskite defects by surface passivation, which agreed with the analysis of PL/TRPL results.

To clarify the effect of APDI modification on photovoltaic performance (PV), inverted PSCs with the architecture of ITO/PTAA/perovskite/C<sub>60</sub>/BCP/Ag were fabricated. Schematic diagrams of the device structure and surface passivation of APDI are shown in Fig. 3a. The cross-sectional SEM (Fig. 3b) image of PSC shows a clear compositional structure with a suitable thickness ( $\sim 680 \text{ nm}$ ) of the perovskite layer.<sup>11</sup> For the regulation of perovskite surface properties, the concentration of functional compounds is extremely critical. Here, the optimal concentration of APDI (0.3 mg/ml) was determined by the

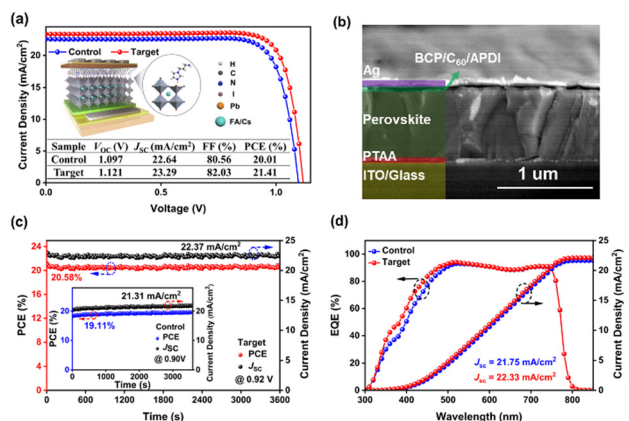


Fig. 3 (a)  $J$ - $V$  curve of PSCs and the illustration of device structure based on APDI modification, (b) cross-sectional SEM image of PSC, (c) stabilized power output at the maximum power point under AM 1.5G and (d) EQE for the control and target devices.

current density-voltage ( $J$ - $V$ ) test, as shown in Fig. S5 and Table S3 (ESI<sup>†</sup>). From Fig. 3a, it can be observed that compared to the PV parameters of the control device ( $V_{oc} = 1.097 \text{ V}$ ,  $J_{sc} = 22.64 \text{ mA cm}^{-2}$ ,  $FF = 80.56\%$ , and  $PCE = 20.01\%$ ), the performance of the target device is significantly enhanced ( $V_{oc} = 1.121 \text{ V}$ ,  $J_{sc} = 23.29 \text{ mA cm}^{-2}$ ,  $FF = 82.03\%$ , and  $PCE = 21.41\%$ ). Additionally, the average values demonstrated improved PV parameters for the target devices (Fig. S6 and Table S4, ESI<sup>†</sup>). The MPP (power output at the maximum power point) measurements for the control (19.11%) and target (20.53%) devices are shown in Fig. 3c. The steady-state PCE and  $J_{sc}$  of the target devices were higher than those of the control devices, and the values matched with the  $J$ - $V$  data. As shown in Fig. 3d, the integrated current (control =  $21.75 \text{ mA cm}^{-2}$  and target =  $22.33 \text{ mA cm}^{-2}$ ) from the external quantum efficiency (EQE) agrees with the  $J_{sc}$  values from the  $J$ - $V$  curves.

To better understand the charge recombination characteristics of the devices, the  $V_{oc}$  and  $J_{sc}$  vs. light intensity were studied. The result of  $J_{sc}$  vs. light intensity demonstrated (Fig. S7a, ESI<sup>†</sup>) a fit slope closer to the value of 1 for the target device ( $\alpha_{control} = 0.962$  and  $\alpha_{target} = 0.976$ ), which indicated that, compared to the control device, the target device had lower bimolecular recombination. Fig. 4a shows that the target device had a smaller slope of  $1.386 \text{ kT/q}$  compared to the pristine one ( $1.629 \text{ kT/q}$ ), indicating that the non-radiative charge recombination of the device was suppressed by the surface passivation of APDI. The electrochemical impedance spectroscopy (EIS) showed that the  $R_s$  ( $R_1$ ) of the target device was lower than that of the control one, while the  $R_{rec}$  ( $R_{rec} = R_2 + R_3$ ) was higher than the control (Fig. 4b).<sup>15</sup> As shown in Fig. S7b (ESI<sup>†</sup>), the target device also illustrated higher  $R_{rec}$  at different bias voltages than the control, which further affirmed the reduced charge recombination at the perovskite/C<sub>60</sub> interface. Furthermore, the Mott-Schottky measurements showed (Fig. 4c) that the target device had a higher built-in potential ( $V_{bi} = 1.04 \text{ V}$ ) than the control one ( $V_{bi} = 1.01 \text{ V}$ ), indicating that there was a stronger charge transfer capability at the interface after APDI

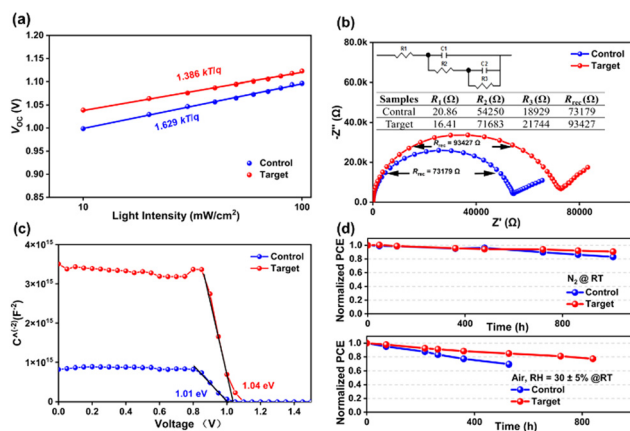


Fig. 4 (a)  $V_{oc}$  vs. light intensity, (b) EIS and (c) Mott-Schottky fitting to the capacitance-voltage plots for the control and target devices. (d) Stability of unencapsulated devices under  $N_2$  and air conditions.



treatment.<sup>16</sup> To deeply illustrate the charge transport of PSCs at the perovskite/C<sub>60</sub> interface, we tested the relationship of photocurrent ( $J_{ph}$ ) vs. effective applied voltage ( $V_{eff}$ ), as shown in Fig. S7c (for more details, see the characterization in ESI†), and the results showed that the exciton dissociation probability ( $P_{diss}$ ) value of the target (~91%) device was higher than that of control (~89%), which indicates that the APDI-modified interface was more favorable for charge transfer to the electrode, thus promoting the reduction of charge recombination.<sup>17</sup>

Considering the stability of the PSCs, we investigated the decay of the PV parameters of the devices in different environments. The results showed that the unencapsulated target device maintained 90% and 78% of the initial PCE after aging under nitrogen or air for 1000 h and 800 h, respectively, while the control device had only 81% and 62%, respectively (Fig. 4d). By performing the contact angle test (Fig. S3, ESI†), it was clear that the perovskite/APDI films showed stronger hydrophobicity, which may be due to the effect of alkyl chains on the APDI. Therefore, this largely enhances the stability of the target devices in both air and nitrogen atmospheres. The decay trend of the remaining parameters ( $V_{oc}$ ,  $J_{sc}$ , FF) is shown in Fig. S8 (ESI†). To further investigate the reason for the degradation of device performance, we examined the variation in XRD parameters during the aging of perovskite films before and after APDI treatment. The results (Fig. S9, ESI†) showed that the pristine perovskite film exhibited a new signal attributed to the PbI<sub>2</sub> after being aged for 3 days in the air, indicating that the decomposition of perovskite film may be due to the vulnerability of defect sites on the perovskite surface to erosion by external factors. The erosion process of the target film by external factors was delayed based on the improvement of perovskite film quality, which was caused by the surface termination passivation effect of APDI and the presence of alkyl chains in APDI.<sup>18</sup>

Overall, we employed an imidazole-based diiodide (APDI) to modulate the terminal environment of the Cs/FA perovskite surface to enhance the inverted PSC performance. Consequently, the APDI-treated device achieved a PCE of 21.41% and exhibited superior stability under air or nitrogen conditions. The reasons for performance enhancement were as follows: (i) the binding of N in APDI and uncoordinated Pb<sup>2+</sup>, which effectively reduces the defect density and the trap-assisted charge recombination; (ii) the acceleration of the efficient charge transport at the perovskite/C<sub>60</sub> interface due to the fine interface properties between perovskite/APDI and C<sub>60</sub>; (iii) the alkyl chains of APDI can enhance the hydrophobicity of perovskite films, thus beneficially reducing the risk of perovskite film being eroded by H<sub>2</sub>O. This study demonstrated a featured recipe for improving PSC performance by introducing ammonium salts with bifunctional groups onto the perovskite surface.

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## Conflicts of interest

There are no conflicts to declare.

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